## Research plan II: Ground state cooling of a sub-mg cantilever

Kentaro Komori Lab seminar 2023/01/27

## Contents

>Introduction of the ground state cooling

Method and previous works

≻My experimental design

## Background (at my previous talk)

The massive quantum (70 pg) and the lightest gravity (90 mg)



## Background (now)

> The massive quantum (16 ug) and the lightest gravity (90 mg)



## Ground state of a mechanical mode

➢Energy eigenvalue



✓ Assuming the equal contribution of the displacement and momentum (strictly correct in the thermal noise limit)

$$\implies m\omega_m^2\langle x^2\rangle = \left(n + \frac{1}{2}\right)\hbar\omega_m$$

Displacement variance  $c_{\infty}$ 

$$\langle x^2 \rangle = \int_0^\infty \frac{d\omega}{2\pi} S_x$$

#### ≻Ground state

- Absolute ground state:  $n = 0 \rightarrow \langle x^2 \rangle = \frac{\hbar}{2m\omega_m}$  (zero-point fluctuation)
- Conventional ground state in optomechanics: n < 1
- The entanglement can keep for a long time enough

## Thermal phonon

► Brownian motion

$$m\omega_m^2 \langle x^2 \rangle_{th} = k_B T = \left( n_{th} + \frac{1}{2} \right) \hbar \omega_m \quad \Longrightarrow \quad n_{th} \approx \frac{k_B T}{\hbar \omega_m}$$

#### ≻Huge thermal phonon

$$T = 300 \text{ K}, \omega_m / 2\pi = 340 \text{ Hz} \longrightarrow n_{th} \sim 10^{10}$$

- ✓  $n_{th} < 1$  at room temperature is achieved by  $\frac{\omega_m}{2\pi} > 6$  THz
- ✓ Laser light (1064 nm  $\leftrightarrow$  282 THz) is not thermally driven
- ✓ Microwave (GHz) should be treated carefully

Requiring the cooling by many orders of magnitudeCryogenic system is not enough

## Damping or cooling

- ≻With or without additional mechanical loss
  - Original thermal noise variance

$$\langle x^2 \rangle_{th} = \int_0^\infty \frac{d\omega}{2\pi} \frac{4k_B T \gamma_m}{m |\omega_m^2 + i \gamma_m \omega - \omega^2|^2}$$

$$=\frac{k_B T}{m\omega_m^2} \qquad \qquad \gamma_m = \frac{\omega_m}{Q_m}$$

✓ Independent of the mechanical loss✓ e.g. Magnet damping



Cooled to the effective temperature  

$$\langle x^2 \rangle_{th} = \int_0^\infty \frac{d\omega}{2\pi} \frac{4k_B T \gamma_m}{m |\omega_m^2 + i \gamma_{eff} \omega - \omega^2|^2}$$
  
 $= \frac{k_B T \gamma_m}{m \omega_m^2 \gamma_{eff}}$   
 $\checkmark$  Effective temperature  
 $\checkmark$  e.g. Active damping via feedback  
 $\checkmark$ 

## Maximum cooling and f-Q criteria

>The mechanical oscillator must keep the "oscillator"

- Effective Q-value should be above the unity,  $Q_{eff} = \frac{\omega_m}{\gamma_{eff}} > 1$
- Over-damped oscillator ( $\gamma_{eff} > \omega_m$ ) is meaningless

≻The ground state cooling requires the f-Q criteria

$$1 > n_{th,eff} = \frac{k_B T \gamma_m}{\hbar \omega_m \gamma_{eff}} > \frac{k_B T \gamma_m}{\hbar \omega_m^2}$$
$$\implies f_m Q_m > 6 \text{ THz} \left(\frac{T}{300 \text{ K}}\right)$$

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## Feedback cooling

>Feedback is a loss-less damping because information is not lost



## Optical spring



## Sideband cooling

≻The upper sideband absorbs the motional energy





✓ The energy absorption leads to the damping

## Feedback v.s. sideband

|      | Feedback cooling  | Sideband cooling  |  |  |  |  |
|------|---|---|--|--|--|--|
| Pros | • Can be used for low-frequency oscillators ( $\omega_m \ll \kappa$ )   | <ul> <li>No feedback of the sensing noises (e.g. shot noise)</li> <li>Low radiation pressure noise</li> </ul>                         |  |  |  |  |
| Cons | <ul> <li>Feedback of the sensing noises</li> <li>Non-negligible radiation pressure noise</li> <li>Shot</li> <li>Radiation ressure the sensing noises</li> </ul> | • Only for high-frequency oscillators<br>$(\omega_m \gtrsim \kappa)$<br>Small energy<br>absorption due to low-<br>frequency sidebands |  |  |  |  |

## Feedback v.s. sideband



 $\checkmark$  The ground state cooling has been mainly achieved by the sideband cooling

## Sideband cooling of the pillar

#### >Planck mass scale optomechanics



 $10^{-3}$ 

10<sup>-35</sup> 3.5780

3.5781

3.5782 3.5783 3.5784

Frequency (MHz)

#### ➢Issues

- Instability of the membrane suspending the pillar (probably due to the anti-spring)
- Only the power of 25 uW was injected, the phonon number stooped at  $\sim 20$
- Ultimately, the back-action limits the phonon number  $n_{ba} \sim 4$

3.5785 3.5786

## Back-action limit

Back-action (radiation pressure noise) gives additional displacement, or phonon

$$n_{ba} = -\frac{\kappa^2 + (\Delta + \omega_m)^2}{4\omega_m \Delta}$$
  
$$\geq \frac{\kappa^2}{2\omega_m^2} \frac{1}{1 + \sqrt{1 + \kappa^2 / \omega_m^2}} \quad \text{at} \ \Delta = -\sqrt{\kappa^2 + \omega_m^2}$$



• Very roughly, the same detuning as the cavity line width is the most efficient and gives the smallest back-action noise

$$n_{ba,min} \sim \frac{\kappa^2}{4\omega_m^2} < 1 \; (\omega_m \gtrsim \kappa)$$

- High resonance
- Resolved sideband regime
- Good cavity

$$n_{ba,min} \sim \frac{\kappa}{2\omega_m} \gg 1 \; (\omega_m \ll \kappa)$$

- Low resonance
- Doppler regime
- Bad cavity

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## Initial plan

#### Similar experiment with sapphire pillar



## ✓ The pillar supported by the bulk is stable

 ✓ The sapphire is due to the large Young's modulus (high resonance), good for f-Q criteria (???)

$$f_m Q_m > 6 \text{ THz}\left(\frac{T}{300 \text{ K}}\right)$$

# 最大値:1 一次位・ 1 最大 公立 公 0.8 公立 〇 0.6 七一ド 35: 2.723E+06 Hz・ 0.4 0.2 0.002 晶々

#### ≻Issues

- Cannot find the pillar mode, the isolation is necessary to have the mode stand out
- The high resonance is not necessarily good

## Phonon number and damping

≻Lower resonance leads to the smaller phonon number

$$n_{th,eff} = \frac{k_B T \gamma_m}{\hbar \omega_m \gamma_{eff}}$$
$$= \frac{k_B T}{\hbar Q_m \gamma_{eff}}$$

$$\gamma_{eff} \sim \frac{3\omega_0 \mathcal{F} P_{circ}}{\pi c^2 m \omega_m}$$

with 
$$\omega_m \sim \kappa$$
,  $\Delta \sim -\kappa$ 

- ✓ Important parameters are
  - Low temperature
  - High Q-value
  - Light mass
  - Low resonance
  - High finesse
  - High intra-cavity power -

while keeping the f-Q criteria

- Large damping

## Current plan

- ➢ Silicon monolithic cantilever
  - High-Q
  - Easy fabrication
  - Relatively low resonance
  - Standing out (the lowest) mode

### ≻Mechanical parameters

- Effective mass: 0.3 mg
- Resonant frequency: 120 kHz
- Q-value: 10<sup>7</sup>



✓ The base plate should be as large as possible to reduce the recoil and the cramp loss

## Q-value

#### ≻Should exceed 10<sup>7</sup>, and possible



J. Microelectromech. Syst. 9, 117 (2000)

Low-temperature force sensitivity was characterized using a bare silicon cantilever with dimensions of 470  $\mu$ m×45  $\mu$ m×1.5  $\mu$ m, a spring constant of 0.07 N/m, and a resonance frequency of 9.8 kHz. The Q of the cantilever resonance was 40 000 at room temperature in vacuum (~10<sup>-5</sup> Torr), and improved to 200 000 at 6 K. Figure 2 shows the thermal

- ✓ The Q-value is linearly increased by the mechanical dimension
- $\checkmark$  The surface loss is diluted by the bulk volume
- ✓ Sub-mm cantilever can have the Q of  $10^7$

## Coating and finesse

#### ≻Crystalline coating

- The typical optical loss  $\sim$  5 ppm at 1550 nm
- The input mirror transmissivity  $\sim 50$  ppm, and other losses  $\sim 50$  ppm in total (conservatory assumption), lead to the finesse  $\sim 63000$

| Supermirror Specifications                       |        |         |                               |   |  |   |   |   |   |  |  |
|--|--------|---------|-------------------------------|---|--|---|---|---|---|--|--|
| Item #s  |        | XM11P8  | XM11R8                        | XM23P8  | XM23R8   | XM12P8  | XM12R8  | XM14P8  | XM14R8  |  |  |
| Center Wavelength                                |        | 1064 nm |                               | 1397 nm   |  | 1550 nm   |   |   |   |  |  |
| Mirror Shape                                     |        | Plano   | Concave                       | Plano   | Concave  | Plano   | Concave   | Plano   | Concave   |  |  |
| Finesse <sup>a</sup>                             |        | 100 000 |                               | 300 000   |  | 200 000   |   | 300 000   |   |  |  |
| Crystalline Coating Reflectance <sup>b</sup>     |        |         | 6 at 1064 nm<br>Central Ø8 mm |   | at 1397 nm<br>Central Ø8 mm                            | > 99.9984% at 1550 nm<br>0° AOI over Central Ø8 mm        |   | <u>&gt; 99.999%</u> at 1550 nm<br>0° AOI over Central Ø8 mm         |   |  |  |
| Crystalline Coating Transmission <sup>b</sup>    |        |         |                               | > 3.5 ppm at Center Wavelength<br>0° AOI over Central Ø8 mm             |  | > 5 ppm at Center Wavelength<br>0° AOI over Central Ø8 mm |   | <u>&gt; 5 ppm at Center Wavelength</u><br>0° AOI over Central Ø8 mm |   |  |  |
| Crystalline Coating Loss Angle <sup>b,c</sup>    |        |         |                               | < 4 x 10 <sup>-5</sup> at 300 K<br>< <u>5 x 10<sup>-6</sup> at 10 K</u> |  |   |   |   |   |  |  |
| Damage Threshold <sup>d</sup>                    | CWe    |         |                               | 46.2 kW/cm (1064 nm, Ø5.5 mm)   |  |   |   |   |   |  |  |
| Damage Threshold*                                | Pulsed |         |                               | 5 J   | 5 J/cm <sup>2</sup> (1030 nm, 10 ns, 10 Hz, Ø0.240 mm) |   |   |   |   |  |  |
| AR Coating Reflectance (Back Side <sup>f</sup> ) |        |         |                               | < 0.1% at Center Wavelength; 0° AOI over Central Ø5 mm                  |  |   |   |   |   |  |  |
| Substrate Material                               |        |         | g                             | <sup>g</sup> Corning 7979 0A IR Fused Silica <sup>g</sup>               |  | Corning 7980 0A   |   | UV Fused Silica <sup>g</sup>  |   |  |  |
| Surface Roughness                                |        |         | 5)                            | Back Side:  | ing: < 1.5 Å (RMS)<br>< 1 Å (RMS)<br>al Ø19.5 mm       | Back Side: <  | ng: < 1.5 Å (RMS)<br>< 1.5 Å (RMS)<br>al Ø19.5 mm | Back Side:  | ng: < 1.5 Å (RMS)<br>< 1 Å (RMS)<br>al Ø19.5 mm |  |  |

## Coating and finesse

>Can be coated on the small area



- Coating area: 0.5 mm x 0.5 mm
- Spatial optical power loss < 0.1 ppm with the designed beam radius  $\sim 80$  um





コーティングが要求仕様を満たすことが 確認できたら、リソグラフィやエッチン グ技術を用いて形状を精密に限定しま す。その後コーティングをGaAsウェハよ り剥離します。当社では、最小Ø20 µm から最大Ø200 mmまでの範囲で、任意 の形状のコーティングが可能です。

## Coating and finesse

- ≻Low mechanical loss
  - Below 10<sup>-5</sup> at cryogenic temperature
- ≻Two dilution
  - Thickness: Coating ~7 um v.s. substrate 0.5 mm  $\alpha_t \sim 0.014$
  - Strain energy:

$$\phi_{total} = C \int \frac{d^2x}{du^2} \phi(u) du$$

The strain energy ratio is only 2.2% at the quarter edge of the cantilever

> In total, the drop of the Q-value is 3%



## Frequency noise

 $\succ$  The sideband from the displacement causes the heating

• Requirement for the ground state cooling:

$$S_x < \frac{\hbar^2}{k_B T m \gamma_m}$$
  $\Box > \sqrt{S_x} < \sqrt{\frac{\hbar^2}{10 k_B T m \gamma_m}} = 2.8 \times 10^{-20} \text{ m/VHz}$   
Requirement on the frequency noise  $n_x < 0.1$ 

• Requirement on the frequency

$$\sqrt{S_{freq}} < 5.3 \times 10^{-4} \text{ Hz}/\sqrt{\text{Hz}}$$



- Round trip length: 1 m
- Finesse: 30000 (cavity pole 5 kHz)

- $\checkmark$  Passive frequency stabilization with the double pass cavity
- ✓ Mephisto-like laser source:  $10^4/f$  Hz/√Hz
- ✓ Suppressing by  $1/20^2$ ,  $2.5 \times 10^{-4}$  Hz/√Hz at 100 kHz

## Experimental setup

>One laser is used as cooling, and the other is used as probing



- ✓ Optical parameters
  - Cooling laser power: 5 mW
  - Cavity length: 1 cm
  - Finesse: 63000
  - Intra-cavity power: 33 W
  - Probing laser power: 0.2 mW

## Goal

#### ► Ground state cooling $10^{-18}$ Shot noise of Free mass SQ, the probing Displacement [m/rHz] 10<sup>-19</sup> In-10<sup>-20</sup> In-20 **Back-action** $n_{ba} = 0.21$ \*\*\*\*\*\*\* ` 10<sup>-20</sup> ⊦ Thermal noise $n_{th,eff} = 0.54$ Mirror thermal $n_{tot} \sim 0.8$ 10<sup>-22</sup> 10<sup>5</sup> $10^{6}$ $10^{4}$ Frequency [Hz]

#### ✓ Future steps

- Discussion on the fabrication
- Q measurement
- Discussion on the coating with CMS (Thorlab)
- Finesse and Q measurement
- Laser selection

## Summary

➤Ground state cooling is equivalent to suppressing the displacement to the level of the zero-point fluctuation

>The feedback or sideband cooling are necessary

➢Proposing sideband cooling of a sub-mg cantilever

> The ground state cooling should be possible